MARKING SCHEME SET 55/1/C

Q. No.	Expected Answer		Mar ks	Total Marks	
Section - A					
Set-1, Q1 Set-2, Q5 Set-3, Q2	Power factor = 1		1	1	
Set-1, Q2 Set-2, Q4 Set-3, Q5	 i) Width of depletion layer will decrease ii) potential barrier will decrease iii) junction will conduct (Any one point) 		1	1	
Set-1, Q3 Set-2, Q2 Set-3, Q4	$\overrightarrow{P} = \in_0 X_e \overrightarrow{E}$ (Also accept if the student writes $\overrightarrow{P} \propto \overrightarrow{E}$	or $\overline{P} = X_e \overline{E}$)	1	1	
Set-1, Q4 Set-2, Q3 Set-3, Q1	Mobility is defined as drift velocity per unor $\mu = \frac{v_d}{E}$ S.I. Unit - m^2/Vs or Cm/Ns	nit electric field	1/2	1	
Set-1, Q5 Set-2, Q1 Set-3, Q3	$\frac{1}{f} = (\mu - 1)(\frac{1}{R_1} - \frac{1}{R_2})$ $\therefore \mu = 1.5$ (Award 1 mark even if direct answer is written)		1/2	1	
	Section	n - B			
Set-1, Q6 Set-2, Q7 Set-3, Q10	Two differences between Interference are Interference 1 All the bright bands are of some	Diffraction			
	 1 All the bright bands are of same intensity. 2 All the bright bands are of same width. 	Intensity of bright bands goes on decreasing with increasing order. Not of same width.			
	3 Dark bands may be completely dark. 4 Number of fringes are more. (Any two) [Award only 1 mark if student draws without writing points]	Less in number.	1×2	2	
	Or				

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		short focal length and	Telescope Objective is of large focal length and large	1/2+ 1/2	
	Working	piece of short focal length and large aperture. $[f_e > f_o]$ It will form magnified	aperture but eye piece of short focal length and short aperture. It will form magnified image of distant object.	1/2+ 1/2	
		to focus of objective	(Objective will form the image of distant object at its focus and image is diminished.)	form.	2
Set-1, Q7 Set-2, Q10 Set-3, Q8	Postulate- Energy is radia	ulate - 1 nula for H'_{α} line - $\frac{1}{2}$ stitution and calculation- $\frac{1}{2}$ ted when an electron jump to the difference in energy	s from a (permitted) higher	1	
	$hv = E_i - E_j$ $\frac{1}{\lambda_{\infty}} = R_H \left[\frac{1}{2^2} - \frac{1}{3^2} \right]$	f		1/2	
	= 1.03 × 10 ⁷ × [Award ½ mark if studen	$\frac{5}{36} \qquad \because \lambda_{\alpha} = 6.99 \times 1$ t only writes $\frac{1}{\lambda} = R_{H} \left[\frac{1}{n_{f}} \right]$	$0^{-7} \text{ m} = 699 \text{ nm}$ $\frac{1}{2} - \frac{1}{n_i 2}$	1/2	2

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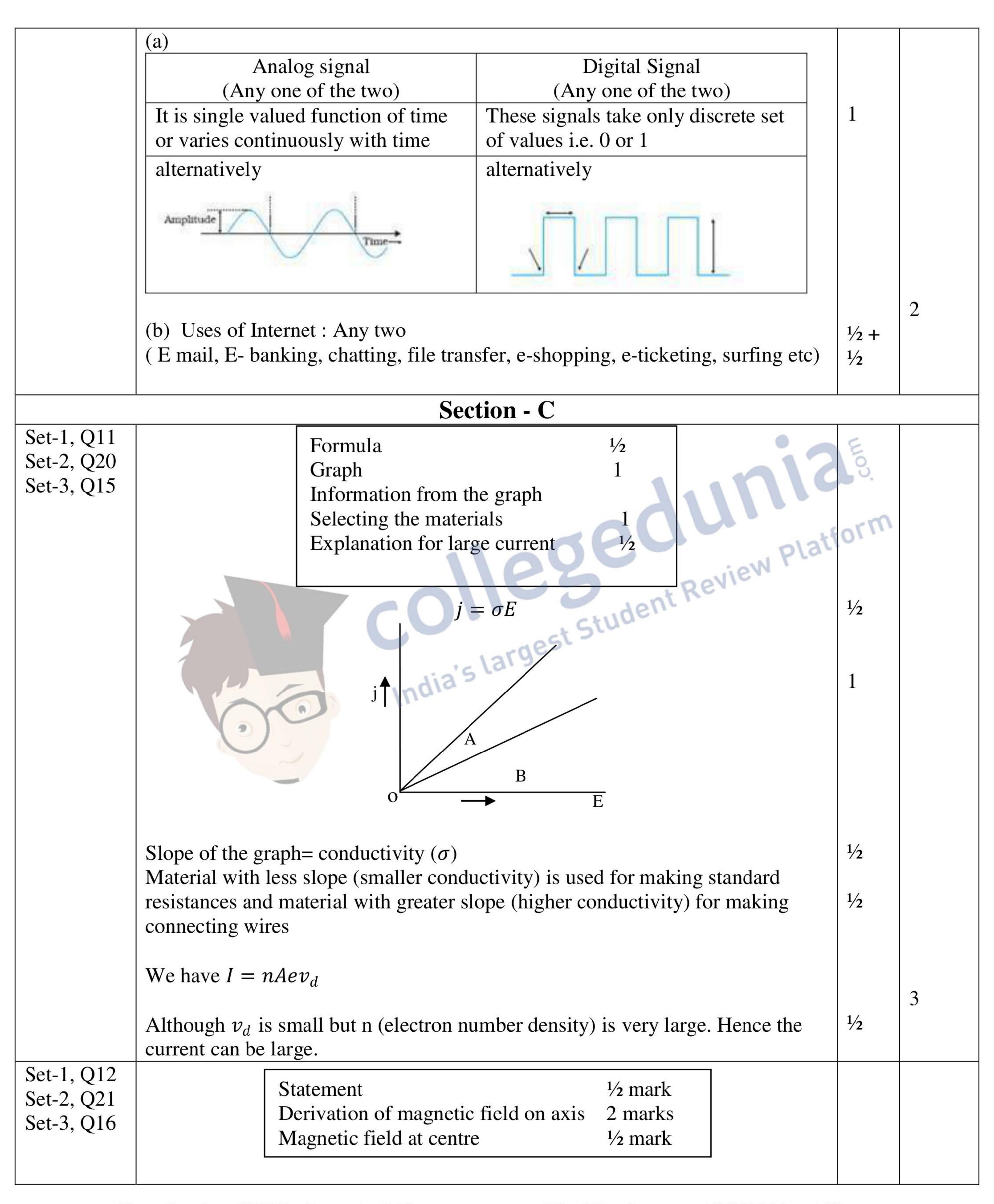


Set-1, O8			
Set-1, Q8 Set-2, Q6	Kirchhoff's laws 1/2+1/2		
Set-3, Q9	To justify them ½+½		
	Kirchhoff's I Law: (JUNCTION LAW) Sum of the incoming currents at a junction = Sum of outgoing currents		
	[Alternatively Algebraic sum of all the currents meeting at a junction in the electrical circuit is zero]	1/2	
	2 nd Law: (LOOP LAW) The algebraic sum of the changes in potential around any closed loop involving resistors and cells in the loop is zero	1/2	
	[Alternatively In any closed electrical part of circuit, sum of the e.m.f s is equal to sum of products of various currents and resistances through which currents pass.]	EO.	
	To justify First law is based on the law of conservation of charge.	1/2 1	
	Second Law is based on the law of conservation of energy.	1/2	2
Set-1, Q9 Set-2, Q8 Set-3, Q7	Formula for de Broglie wavelength – 1 Calculation and result – 1 Formula used $\lambda = \frac{h}{mv} = \frac{h}{\sqrt{2mE}}$	1	
	$\frac{\lambda_1}{\lambda_2} = \sqrt{\frac{E_2}{E_1}}$ since $E_n \propto \frac{1}{n^2}$	1/4	
	For $n = 2$ $E_2 = \frac{E_1}{4}$	72	
	$\therefore \frac{\lambda_1}{\lambda_2} = \sqrt{\frac{1}{4}} = \frac{1}{2}$	1/2	2
	[Award ½ mark if the student only writes $\lambda = \frac{h}{m}$]		
	Also accept any other correct alternative answer.		
Set-1, Q10 Set-2, Q9 Set-3, Q6	(a) Difference between Analog and Digital signal 1 (b) Any two uses of internet 1		
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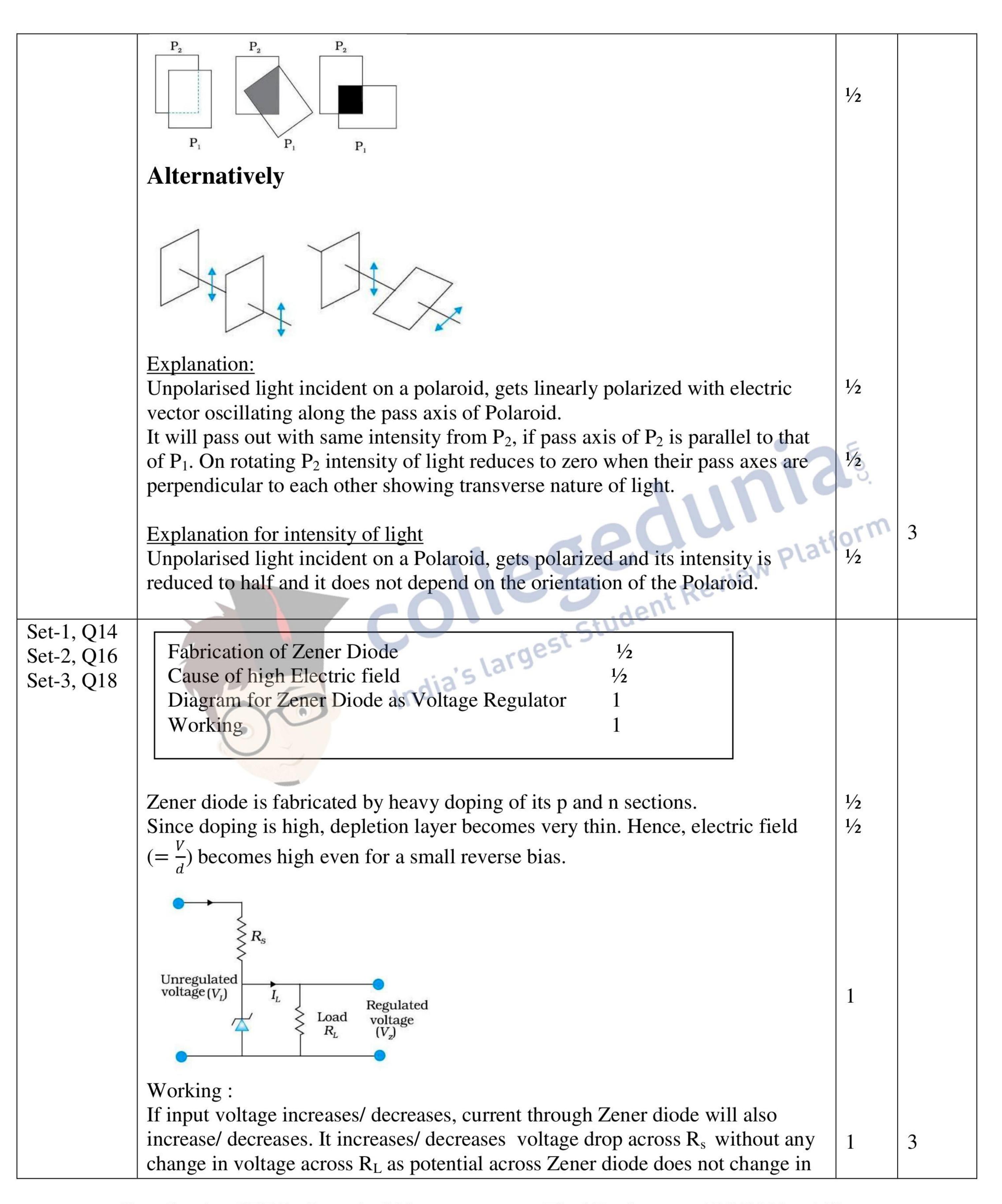


	Biot Savart's law $\overrightarrow{dB} \propto I \frac{\overrightarrow{dl} \times \overrightarrow{r}}{r^3}$ Or $\overrightarrow{dB} = \frac{\mu_o}{4\pi} I \frac{\overrightarrow{dl} \times \widehat{r}}{r^2}$	1/2	
	[Also accept if the student writes $dB \propto I$, $dB \propto dl$ and $dB \propto \frac{1}{r^2}$]		
	Derivation	1/2	
	The resultant magnetic field will be along the axis as the perpendicular (to the axis) components cancel out in pairs. $B = \int_{0}^{e\pi R} dB \cos \theta$ $= \int_{0}^{2\pi R} \frac{\mu_0}{a} \frac{Idl}{a} \frac{R}{a} $	1/2	
	$= \frac{\mu_0 I}{4\pi} \frac{2\pi R^2}{(R^2 + x^2)^{3/2}} = \frac{\mu_0 I R^2}{2(R^2 + x^2)^{3/2}}$	1/2	
	At centre, $x = 0$ $\therefore B_0 = \frac{\mu_0 I}{2R}$	1/2	3
Set-1, Q13 Set-2, Q22 Set-3, Q17	Polaroid Transverse nature of light Required Explanation 1 1 1 1		
	Polaroid consists of long chain molecules aligned in a particular direction Transverse nature of light.	1	

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	breakdown region giving the regulated output voltage.		
	OR		
	(a) Diagram Formation of depletion region Potential barrier b) Effect on barrier potential 1/2 1 1 1/2 1 1 1 1 1 1 1 1 1 1 1 1 1		
	a) Electron drift ← Electron diffusion		
	p	1/2	
	Explanation Due to concentration gradient across p and n sides, holes from p diffuse into n	orm	
	section and leave behind ionized acceptor (negatively) ions which are immobile. As holes continue to diffuse from p to n, a layer of negative charge on p side of junction is formed. Similarly, the diffusion of electrons from n to p will form a positive charge space region on the n side. The space charge region on either side of the junction which gets devoid of mobile charge carrier is known as the depletion layer .	1	
	The loss of electrons from n side and holes from p side cause a potential difference across the junction. This is known as the called barrier potential.	1/2	
	b) Barrier potential decreases in forward bias .	1/2	
	Barrier potential increases in reverse bias.	1/2	3
Set-1, Q15 Set-2, Q17 Set-3, Q11	Effect in each case 1½ Justification in each case 1½		
	i) Anode current will increase with increase of intensity More is intensity of light, more is the number of photons and hence more number of electrons are emitted	1/2	
	ii) No effect	1/2	

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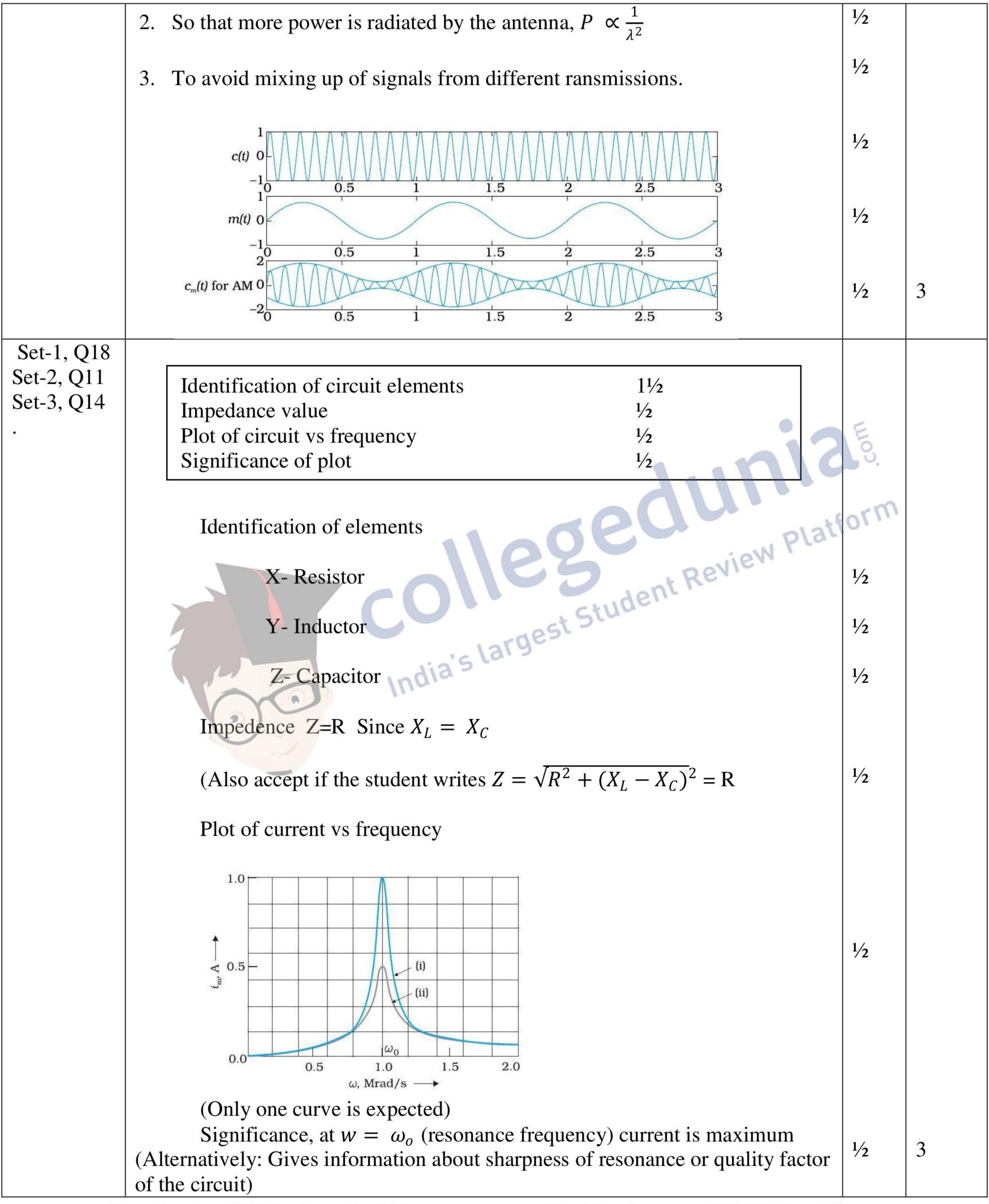


	Frequency of light affects the maximum K.E. of the emitted photoelectrons.	1/2	
	iii) Anode current will increase with anode potential More anode potential will accelerate the electrons more till it attains a saturation value and get them collected at the anode at a faster rate.	1/2 1/2	3
Set-1, Q16 Set-2, Q18 Set-3, Q12	Active state 1/2 Circuit diagram 1 Working 1/2 Reasons in each case 1		
	Active State:		
	When the emitter base junction is forward biased and the base collector junction is reverse biased with $V_i > 0.6V$ or $V_i > 0.3V$. (Also accept any other correct answer) Diagram:	1/2	
	V_{i} V_{BB} V_{CC} $V_$	1	
	Explanation: If V_i is +ve or -ve, changes in V_{BE} will produce changes in I_c and hence changes in V_{CE} which will appear in amplified form	1/2	
	Base is thin so that there are few majority carriers in it.	1/2	
	Emitter is heavily doped so that it supplies more number of majority charge carriers. (Note: Award 1 mark if the student writes the reason for any one case)	1/2	
Set-1, Q17 Set-2, Q19 Set-3, Q13	Factors for need of modulation 1½ Sketch of carrier wave, modulating wave and AM wave 1½		3
	Need of Modulation: 1. To have smaller height of antenna $[h \sim \frac{\lambda}{4}]$	1/2	

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Set-1, Q19			
Set-2, Q12	Equation of β^+ decay		
Set-3, Q21	Identification ½		
	Calculation of mass defect		
	Calculation of Q value		
	Equation ${}^{11}_{6}C \rightarrow {}^{11}_{5}X + i^e + v + Q$	1	
	(Also accept if the student does not write v or Q on the R.H.S.)		
	X is an isobar	1/2	
	Mass defect $(\Delta m) = m\binom{11}{6}C - m\binom{11}{5}X$	1/2	
	= (11.011434 - 11.009305)u		
	= 0.002129 u	1/2	
	$Q = \Delta m \times 931.5 \text{ MeV}$	-rm	
	$= 0.002129 \times 931.5 \text{ MeV}$ = 1.98 MeV	1/2	3
Set-1, Q20	crude		
Set-2, Q13	Calculation to find image formed by lens 1½ Noture of image		
Set-3, Q22	Nature of image Distance of mirror from lens 1/2		
	For lens $\frac{1}{v} - \frac{1}{u} = \frac{1}{f}$	1/2	
	$\left \frac{1}{v} - \frac{1}{-15} \right = \frac{1}{+10}$	1/2	
	$\left \frac{1}{v} + \frac{1}{15} \right = \frac{1}{10}$	1/2	
	$\therefore v = 30 \text{ cm}$	1/2	
	Nature of image- real, magnified	95 (25 TA)	
	Final image formed will be at the object itself only if image formed by lens is at the position of centre of curvature of mirror	1/2	
	ine position of centre of curvature of filling	1/2	
	D = (30 + R)cm = (30 + 20)cm = 50 cm (Distance of mirror from lens)		3

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Set-1, Q21 Set-2, Q14 Set-3, Q19	Arranging in order Production of infrared waves Role of infrared waves in Earth's warmth and physical therapy Gamma(γ) rays, X-rays, Microwaves, Radiowaves	1½	
	Infrared rays are produced by hot bodies / vibration of atoms and molecules	1/2	
	Infrared rays: (i) Maintain Earth's warmth through green house effect	1/2	
	(ii) Produce heat	1/2	3
Set-1, Q22 Set-2, Q15 Set-3, Q20	Process of charging capacitor Effect of dielectric on (i) Electric field and justification Process of charging Process of charging The electrons, from the plate of the capacitor, which is connected to the positive terminal of the battery, move towards the battery. The reverse happens at the other plate. Hence, the plates get positively and negatively charged respectively. Effect of dielectric (a) Electric fields decreases Justification Because initially $E_1 = \frac{\sigma}{\varepsilon_0}$ and finally $E_2 = \frac{1}{K} \cdot \frac{\sigma}{\varepsilon_0}$, $E = \frac{E_1}{K}$	1/2 5. 1/2 1/2 1/2	
	(b) Energy stored increases	1/2	
	New capacitance $C = \left(\frac{\varepsilon_0 A}{2d}\right) k$ $= \frac{K}{C} \qquad \therefore C < C$	1/2	3
	$= \frac{R}{2}C_o, \therefore C < C_o$ Initially Energy = $\frac{Q^2}{2C}$ and Energy = $\frac{Q^2}{C} \cdot \frac{2}{K}$ as $1 < K < 2$		
	Section – D		
Set-1, Q23 Set-2, Q23 Set-3, Q23	Necessity Explanation; low power factor implies large power loss? Two values each displayed by Ajit and his uncle 1+1		

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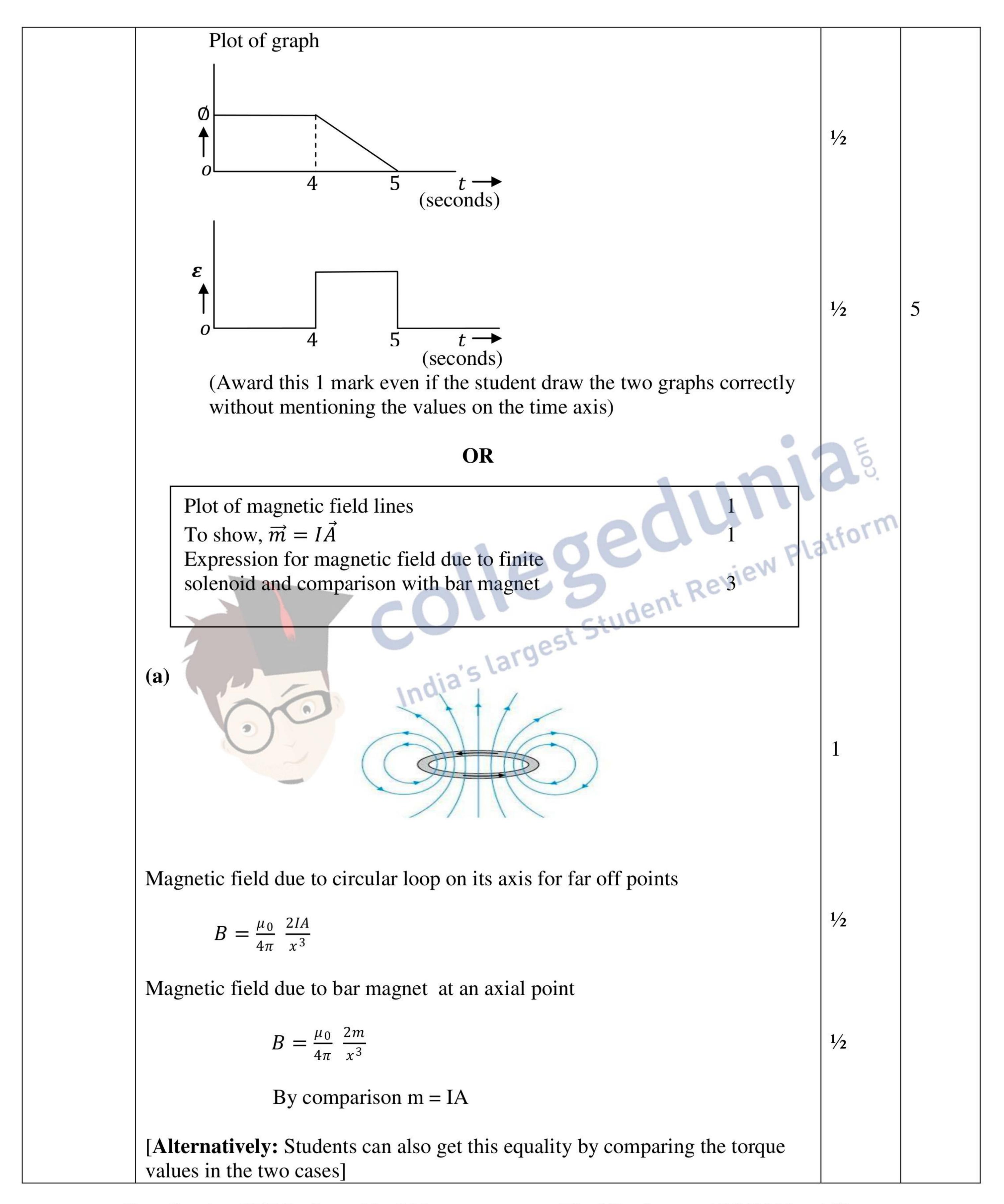


		1	1
	 a) For the same power at high voltage, current in the transmission wires becomes smaller. ∴ power loss is less 	1/2 1/2	
	[Award ½ mark if the student just writes $P = I^2R$]		
	b) If power factor is less, current in the cables is more so power loss is more [Alternately $P_{av} = E_v I_v \cos \theta$	1	
	If $\cos \theta$ is less, I_v is more so power loss is more] (Award $\frac{1}{2}$ mark if the student just writes $P = E_E I_v \cos \theta$		
	c) Values displayed By Ajit (Any two) – Social Awareness, understanding nature, concern for society	1/2 +1/2	
	By Uncle- Knowledgeable, professional honesty, concern for society. (Also accept other suitable values)	1/2 +1/2	4
	Section - E	atforni	
Set-1, Q24 Set-2, Q26 Set-3, Q25	Definition of self-inductance Expression for energy stored Direction of induced current Duration of induced current Graphs of magnetic flux and induced e.m.f 1 2 1/2 1/2 1/2 1		
	a) Self inductance of a coil is numerically equal to magnetic flux linked with the coil when unit current passes through it. $L = \frac{\varphi}{I}$		
	Alternately Self inductance of a coil is numerically equal to induced e.m.f. produced in it when rate of change of current is unity in it.	1	
	Expression for energy Induced e.m.f. produced in coil, $\varepsilon = -L \frac{dI}{dt}$	1/2	
	∴ work done by the source, $dw = +\varepsilon I dt = LIdI$ $W = \int_0^I LIdI = \frac{1}{2}LI^2$	1/2	
	b) Direction of induced current – clockwise (MNOP)	1/2+1/2	
	[A student can also show the direction in the diagram itself]	1/2	
	Duration of induced current - 1s	1/2	
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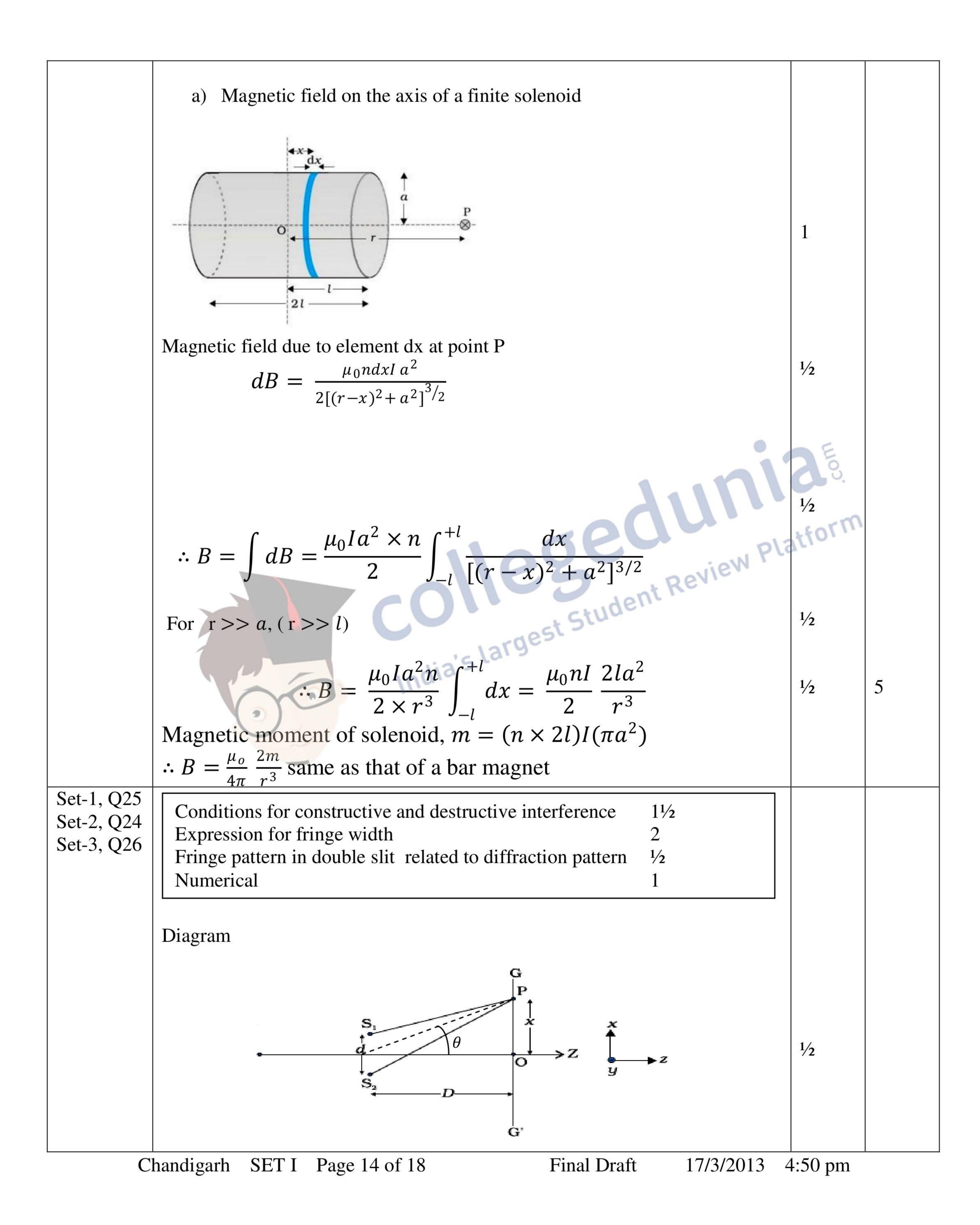
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(a) Path difference $(\Delta) = S_2 P - S_1 P = d \sin \theta = \frac{dx}{D}$
For constructive interference, $\Delta = n\lambda [n = 0,1,2]$

Destructive interference,
$$\Delta = (2n - 1)\frac{\lambda}{2}[n = 1,2..]$$

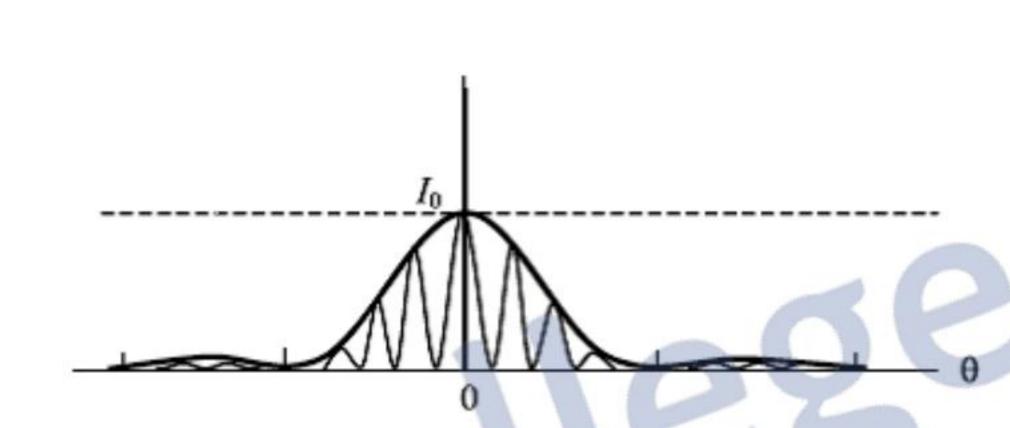
For bright bands,
$$\Delta = n\lambda = \frac{x_n d}{D}$$
 or $x_n = \frac{n\lambda D}{d}$

For bright bands,
$$\Delta = n\lambda = \frac{\Delta}{D}$$
 or $x_n = \frac{\Delta}{d}$

For dark bands,
$$\Delta = (2n-1)\frac{\lambda}{2} = \frac{x_n d}{D}$$
 or $x_n = (2n-1)\frac{\lambda D}{2d}$

Fringe width
$$\beta = X_n - X_{n-1} = \frac{\lambda D}{d}$$

b)



[Alternately

It is a broader diffraction peak in which there appears several fringes of smaller width due to double slit interference pattern]

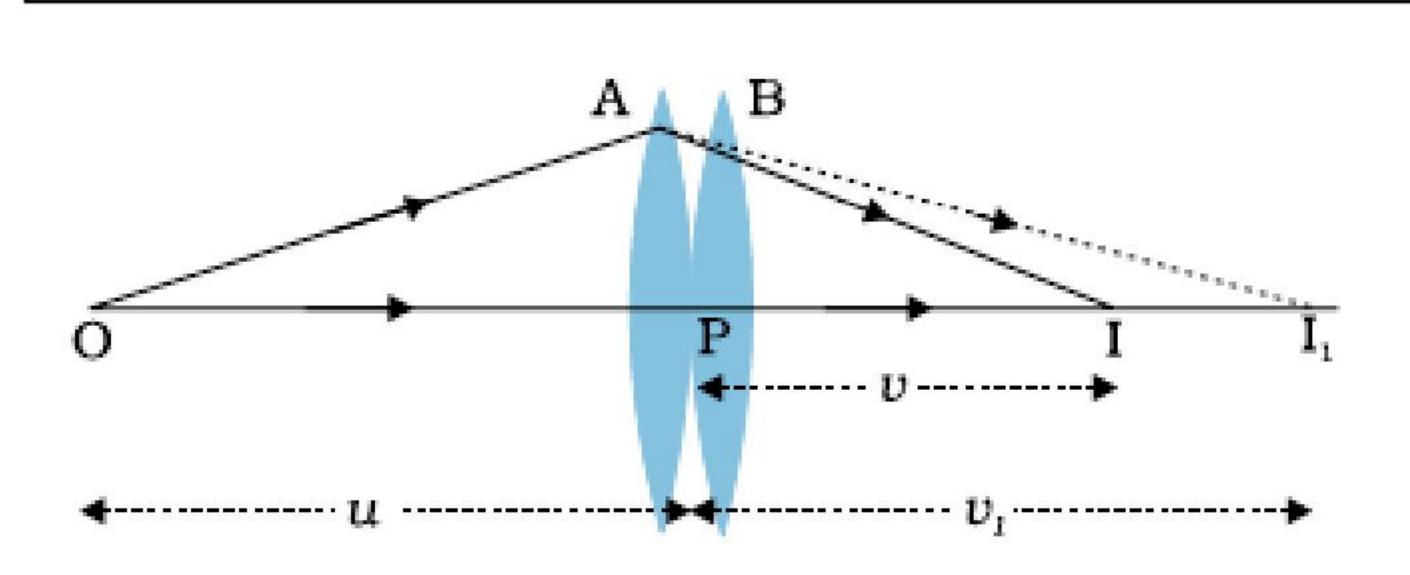
(c) 10β = width of central maxima $10^{\frac{D\lambda}{-}} = 2^{\frac{D\lambda}{-}}$

$$10\frac{D\lambda}{d} = 2\frac{D\lambda}{a}$$

$$a = \frac{d}{5} = \frac{1}{5}mm = 0.2 \ mm$$

OR

Diagram for image formation	1/2
Derivation for combines focal length	11/2
Ray diagram through prism	1
Calculation of angle of incidence and angle of deviation	2



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		1	
	For First lens $\frac{1}{v_1} - \frac{1}{u} = \frac{1}{f_1}$ (i)	1/2	
	For Second lens $\frac{1}{v} - \frac{1}{v_1} = \frac{1}{f_2}$ (ii)	1/2	
	By adding i) and ii) $\frac{1}{v} - \frac{1}{u} = \frac{1}{f_1} + \frac{1}{f_2}$	1/2	
	Or $\frac{1}{f} = \frac{1}{f_1} + \frac{1}{f_2}$		
	b) Ray Diagram		
	P S	as.	
	Given A=60°, $\mu = \sqrt{3}$ It is minimum deviation position of prism,	tto.	
	$\therefore r = \frac{A}{2} = 30^{\circ}$ India's largest	1/2	
	$\mu = \frac{1}{\sin r}$ $\therefore \sqrt{3} \times \sin 30 = \sin i$	1/2	
	$\Rightarrow i = 60^{\circ}$ $\therefore e = 60^{\circ}$	1/2	
	i + e = A + D $60 + 60 = 60 + D : D = 60^{\circ}$	1/2	5
	Alternately		
	$[i = \frac{A + D_m}{2} \therefore D_m = 60^\circ]$		
Set-1, Q26 Set-2, Q25 Set-3, Q24	Expression for potential energy Numerical 2		
	a) Expression for potential energy i) To bring charge q_1 from ∞ to point($\overrightarrow{r_1}$) Work done = $W_1 = q_1 V(r_1)$	1/2	
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ii) To bring charge q_2 from ∞ to point $(\overrightarrow{r_2})$ Work done = $W_2 = q_2 V(r_2) + \frac{1}{4\pi \varepsilon_o} \cdot \frac{q_1 q_2}{r_{12}}$	1/2	
Ka_1a_2	/ 2	

: Potential energy
$$U = W_1 + W_2 = q_1 V(r_1) + q_2 V(r_2) + \frac{Kq_1q_2}{r_{12}}$$

b)
$$U_{l} = \frac{1}{4\pi\varepsilon_{o}} \left[\frac{Q \times 2Q}{l} + \frac{Q(-3)Q}{l} + \frac{2Q \times (-3)Q}{l} \right]$$

$$= -\frac{1}{4\pi\varepsilon_{o}} \frac{7Q^{2}}{l}$$

$$U_f = \frac{1}{4\pi\varepsilon_o} \left[\frac{Q \times 2Q}{\frac{l}{2}} + \frac{Q(-3)Q}{\frac{l}{2}} + \frac{2Q \times (-3)Q}{\frac{l}{2}} \right]$$
$$= -\frac{1}{4\pi\varepsilon_o} \frac{14Q^2}{l}$$

$$W = U_f - U_i = -\frac{1}{4\pi\varepsilon_o} \frac{7Q^2}{l}$$

(If a student writes $U_i = \frac{1}{4\pi\varepsilon_o} \left[\sum \sum \frac{q_i q_j}{r_{ij}} \right]$, award ½ mark)

Electric flux through a given area is defined as the number of electric field lines crossing normally through that area

[Alternately,

Electric flux is the surface integral of electric field over the surface

$$\Phi = \oint \vec{E} \cdot \overrightarrow{ds}$$

S.I. unit -
$$Nm^2C^{-1}$$
 or Vm

Gauss Law: Electric flux through a given closed surface is $\frac{1}{\varepsilon_o}$ times the charge enclosed by the closed surface

[Alternatively: $\phi = \frac{q}{\varepsilon_0}$]

Flux of a point charge placed at the centre of cube = $\frac{q}{\varepsilon_0}$

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	As the Electric field is radial and inversely proportional to the square of distnce. Therefore, it is independent of shape and size. The number of electric field lines, crossing normally through a closed surface depends only on the charge enclosed by it.	1	5	
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